# NSN 5962-01-355-5501

Memory Microcircuit - Page 1 of 1



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# Body Length:

0.400 inches

#### **Body Width:**

0.255 inches

# Body Height:

0.135 inches

#### **Operating Tempurature Range:**

-40.0/+85.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

5895-01-340-9279 base station, co

#### Features Provided:

Electrostatic sensitive and monolithic and positive outputs and erasable

#### Inclosure Material:

Plastic

## Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

# Input Circuit Pattern:

2 input

# **Current Rating Per Characteristic:**

3.00 milliamperes reverse current, dc absolute

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 6.5 volts power source

# Time Rating Per Chacteristic:

1000.00 nanoseconds delay

#### Memory Device Type:

Eeprom

#### **Terminal Type And Quantity:**

8 printed circuit

Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

# Fiig:

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